## imall

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### Vishay Semiconductors



## Infrared Emitting Diode, RoHS Compliant, 875 nm, GaAIAs



TSTA7300 is an infrared, 875 nm emitting diode in GaAlAs technology in a hermetically sealed TO-18 package with

#### FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- Peak wavelength:  $\lambda_p = 875 \text{ nm}$
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity:  $\phi = \pm 12^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

#### APPLICATIONS

• Radiation source near infrared range

# PRODUCT SUMMARY COMPONENT Ie (mW/sr) φ (deg) λP (nm) tr (ns) TSTA7300 20 ± 12 875 600

#### Note

lens.

DESCRIPTION

Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION |           |                              |              |  |  |  |  |
|----------------------|-----------|------------------------------|--------------|--|--|--|--|
| ORDERING CODE        | PACKAGING | REMARKS                      | PACKAGE FORM |  |  |  |  |
| TSTA7300             | Bulk      | MOQ: 1000 pcs, 1000 pcs/bulk | TO-18        |  |  |  |  |

#### Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS            |                                |                   |               |      |  |  |  |
|-------------------------------------|--------------------------------|-------------------|---------------|------|--|--|--|
| PARAMETER                           | TEST CONDITION                 | SYMBOL            | VALUE         | UNIT |  |  |  |
| Reverse voltage                     |                                | V <sub>R</sub>    | 5             | V    |  |  |  |
| Forward current                     |                                | l <sub>F</sub>    | 100           | mA   |  |  |  |
| Peak forward current                | $t_p/T=0.5,t_p\leq 100\;\mu s$ | I <sub>FM</sub>   | 200           | mA   |  |  |  |
| Surge forward current               | $t_p \le 100 \ \mu s$          | I <sub>FSM</sub>  | 2.5           | А    |  |  |  |
| Power dissipation                   |                                | Pv                | 180           | mW   |  |  |  |
|                                     | $T_{case} \le 25 \ ^{\circ}C$  | Pv                | 500           | mW   |  |  |  |
| Junction temperature                |                                | Тj                | 100           | °C   |  |  |  |
| Storage temperature range           |                                | T <sub>stg</sub>  | - 55 to + 100 | °C   |  |  |  |
| Thermal resistance junction/ambient | leads not soldered             | R <sub>thJA</sub> | 450           | K/W  |  |  |  |
| Thermal resistance junction/case    | leads not soldered             | R <sub>thJC</sub> | 150           | K/W  |  |  |  |

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified





## **TSTA7300**

Infrared Emitting Diode, RoHS Compliant, Vishay Semiconductors 875 nm, GaAlAs

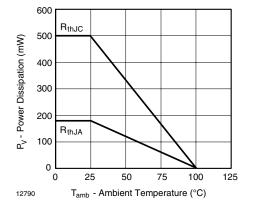


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

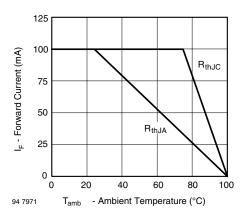


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS                 |                                                         |                   |      |       |      |       |  |
|---------------------------------------|---------------------------------------------------------|-------------------|------|-------|------|-------|--|
| PARAMETER                             | TEST CONDITION                                          | SYMBOL            | MIN. | TYP.  | MAX. | UNIT  |  |
| Forward voltage                       | $I_F = 100 \text{ mA}, t_p \le 20 \text{ ms}$           | V <sub>F</sub>    |      | 1.4   | 1.8  | V     |  |
| Breakdown voltage                     | I <sub>R</sub> = 100 μA                                 | V <sub>(BR)</sub> | 5    |       |      | V     |  |
| Junction capacitance                  | V <sub>R</sub> = 0 V, f = 1 MHz, E = 0                  | Cj                |      | 20    |      | pF    |  |
| Radiant intensity                     | $I_F$ = 100 mA, $t_p \le$ 20 ms                         | l <sub>e</sub>    | 10   | 20    | 50   | mW/sr |  |
| Radiant power                         | $I_F$ = 100 mA, $t_p \le$ 20 ms                         | φe                |      | 10    |      | mW    |  |
| Temperature coefficient of $\phi_{e}$ | I <sub>F</sub> = 100 mA                                 | TKφ <sub>e</sub>  |      | - 0.7 |      | %/K   |  |
| Angle of half intensity               |                                                         | φ                 |      | ± 12  |      | deg   |  |
| Peak wavelength                       | I <sub>F</sub> = 100 mA                                 | λρ                |      | 875   |      | nm    |  |
| Spectral bandwidth                    | I <sub>F</sub> = 100 mA                                 | Δλ                |      | 80    |      | nm    |  |
| Rise time                             | I <sub>F</sub> = 100 mA                                 | t <sub>r</sub>    |      | 600   |      | ns    |  |
|                                       | $I_F = 1.5 \text{ A}, t_p/T = 0.01, t_p \le 10 \ \mu s$ | tr                |      | 300   |      | ns    |  |
| Virtual source diameter               |                                                         | d                 |      | 1     |      | mm    |  |

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified

#### **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

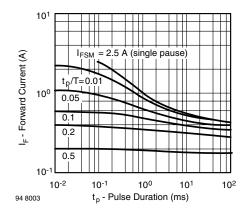


Fig. 3 - Pulse Forward Current vs. Pulse Duration

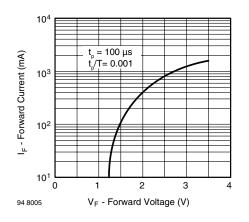
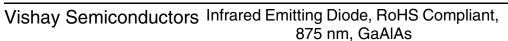


Fig. 4 - Forward Current vs. Forward Voltage

## **TSTA7300**



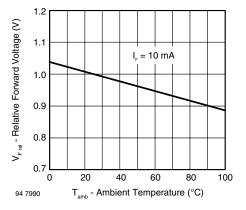


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

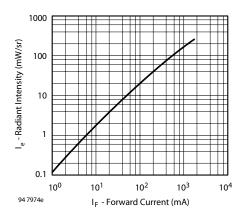


Fig. 6 - Radiant Intensity vs. Forward Current

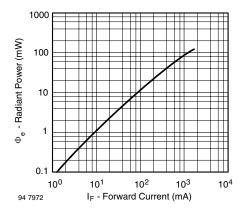


Fig. 7 - Radiant Power vs. Forward Current

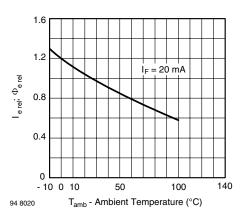


Fig. 8 - Rel. Radiant Intensity/Power vs. Ambient Temperature

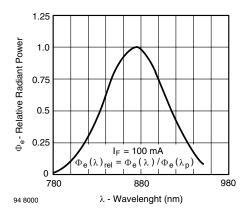


Fig. 9 - Relative Radiant Power vs. Wavelength

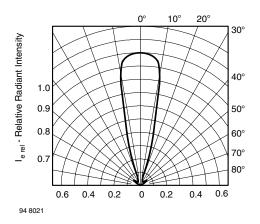


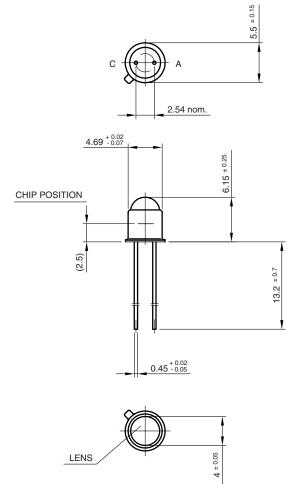
Fig. 10 - Relative Radiant Intensity vs. Angular Displacement





Infrared Emitting Diode, RoHS Compliant, Vishay Semiconductors 875 nm, GaAlAs

#### **PACKAGE DIMENSIONS** in millimeters





technical drawings according to DIN specifications

Drawing-No.: 6.503-5022.01-4 Issue: 2; 24.08.98 96 12179



Vishay

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